Diode Semiconductor Device - Page 1 of 1



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Inclo	sure Material:
Glass	
	all Length:
) inches
	inal Length:
) inches
	all Diameter:
) inches
Joint	Electronic Device Engineering Council/jedec/case Outline Designation:
Do-14	
Mour	nting Method:
Term	-
	ures Provided:
	netically sealed case
	iconductor Material:
Silico	n
Volta	ge Rating In Volts Per Characteristic:
6.2 ı	regulator voltage
Volta	ige Tolerance In Percent:
-5.0/+	⊦ 5.0
Curre	ent Rating Per Characteristic:
1.00 ı	milliamperes source cutoff current horsepower metric
Powe	er Rating Per Characteristic:
600.0) milliwatts small-signal input power, common-collector preset
Maxii	mum Operating Tempurature Per Measurement Point:
175.0) degrees celsius ambient air
Term	inal Type And Quantity:
2 unir	nsulated wire lead
Shelf	f Life:
N/a	
Unit	Of Measure:
Demi	ilitarization:
No	
Fiig:	
	a0